BUK7608-40B



N-channel TrenchMOS standard level FET

Rev. 04 — 24 September 2008

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Q101 compliant

- Suitable for standard level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

1.3 Applications

- 12 V loads
- Automotive systems

- General purpose power switching
- Motors, lamps and solenoids

1.4 Quick reference data

Table 1. Quick reference

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|--|---|-----|-----|-----|-----|------|
| V_{DS} | drain-source voltage | $T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$ | | - | - | 40 | V |
| I _D | drain current | V_{GS} = 10 V; T_{mb} = 25 °C; see <u>Figure 1</u> ; see <u>Figure 3</u> ; | [1] | - | - | 75 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | | - | - | 157 | W |
| Avalanci | he ruggedness | | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I_D = 75 A; $V_{sup} \le 40$ V; R_{GS} = 50 Ω ; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped | | - | - | 241 | mJ |
| Dynamic | characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $V_{GS} = 10 \text{ V; } I_D = 25 \text{ A;}$ $V_{DS} = 32 \text{ V; } T_j = 25 \text{ °C; see}$ <u>Figure 14</u> | | - | 12 | - | nC |
| Static ch | aracteristics | | | | | | |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see <u>Figure 12</u> ; see <u>Figure 11</u> | | - | 6.6 | 8 | mΩ |

^[1] Continuous current is limited by package.



2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|------------------|--------------------|----------------------------------|
| 1 | G | gate | | | |
| 2 | D | drain | [1] | mb | D D |
| 3 | S | source | | | $G \longrightarrow \overline{A}$ |
| mb | D | mounting base; connected to drain | se; connected to | | mbb076 S |
| | | | | SOT404 (D2PAK) | |

^[1] It is not possible to make a connection to pin 2.

3. Ordering information

Table 3. Ordering information

| Type number | | | |
|-------------|-------|--|---------|
| | Name | Description | Version |
| BUK7608-40B | D2PAK | Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--|-----|-----|-----|------|
| V_{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | | - | 40 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20 \text{ k}\Omega$ | | - | 40 | V |
| V_{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | T_{mb} = 25 °C; V_{GS} = 10 V; see <u>Figure 1</u> ; see <u>Figure 3</u> ; | [1] | - | 101 | Α |
| | | $T_{mb} = 100 ^{\circ}\text{C}$; $V_{GS} = 10 ^{\circ}\text{V}$; see Figure 1; | [1] | - | 71 | Α |
| | | T_{mb} = 25 °C; V_{GS} = 10 V; see <u>Figure 1</u> ; see <u>Figure 3</u> ; | [2] | - | 75 | Α |
| I_{DM} | peak drain current | T_{mb} = 25 °C; $t_p \le 10 \mu s$; pulsed; see <u>Figure 3</u> | | - | 407 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | | - | 157 | W |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| T _j | junction temperature | | | -55 | 175 | °C |
| Source-dra | ain diode | | | | | |
| I _S | source current | T _{mb} = 25 °C; | [1] | - | 101 | Α |
| | | T _{mb} = 25 °C; | [2] | - | 75 | Α |
| I _{SM} | peak source current | $t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$ | | - | 407 | Α |

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|--|--|-----|-----|------|
| Avalanche | ruggedness | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I_D = 75 A; $V_{sup} \le$ 40 V; R_{GS} = 50 Ω ; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped | - | 241 | mJ |

- [1] Current is limited by power dissipation chip rating.
- [2] Continuous current is limited by package.

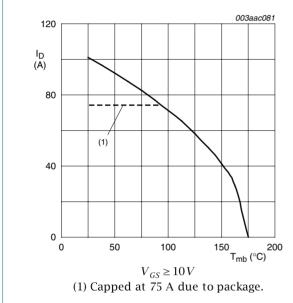


Fig 1. Continuous drain current as a function of mounting base temperature

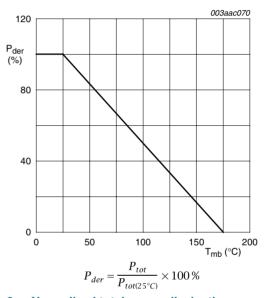
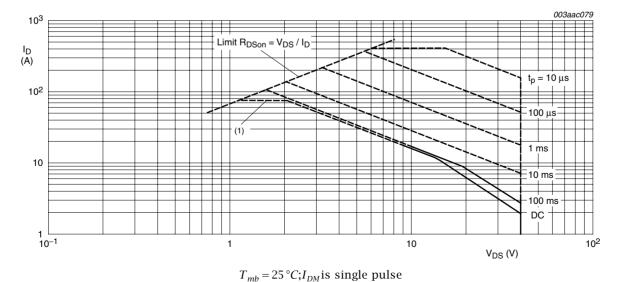


Fig 2. Normalized total power dissipation as a function of solder point temperature



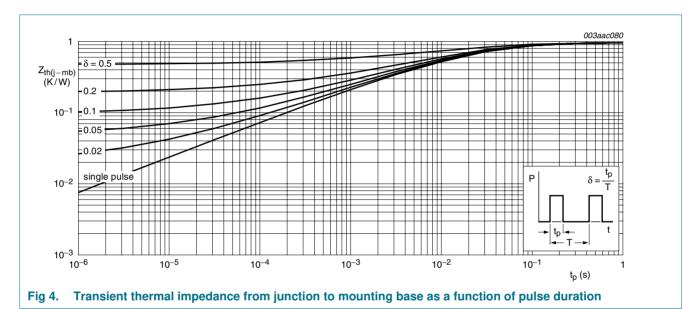
(1) Capped at 75 A due to package.

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-s

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|---|--|-----|-----|------|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | mounted on a printed-circuit board; minimum footprint | - | 50 | - | K/W |
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | see Figure 4 | - | - | 0.95 | K/W |



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6. Characteristics

Table 6. Characteristics

| Table 6. | Characteristics | | | | | |
|---------------------|--|---|-----|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| | racteristics | | | | | |
| $V_{(BR)DSS}$ | drain-source | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | 40 | - | - | V |
| breakdown voltage | | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$ | 36 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold $I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = 25 \text{ °C}$; see voltage Figure 9; see Figure 10 | | 2 | 3 | 4 | V |
| | | $I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = -55 \text{ °C}$; see Figure 9; see Figure 10 | - | - | 4.4 | V |
| | | $I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = 175$ °C; see Figure 9; see Figure 10 | 1 | - | - | V |
| I _{DSS} | drain leakage current | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | 0.02 | 1 | μΑ |
| | | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$ | - | - | 500 | μΑ |
| I _{GSS} | gate leakage current | $V_{DS} = 0 \text{ V}; V_{GS} = 20 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nA |
| | | $V_{DS} = 0 \text{ V}; V_{GS} = -20 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nA |
| R_{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; see Figure 11; see Figure 12 | - | - | 15.2 | mΩ |
| | | V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see Figure 12; see Figure 11 | - | 6.6 | 8 | mΩ |
| Dynamic | characteristics | | | | | |
| Q _{G(tot)} | total gate charge | $I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$ | - | 36 | - | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C; see <u>Figure 14</u> | - | 9 | - | nC |
| Q _{GD} | gate-drain charge | | - | 12 | - | nC |
| C _{iss} | input capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz};$ | - | 2017 | 2689 | pF |
| C _{oss} | output capacitance | T _j = 25 °C; see <u>Figure 15</u> | - | 486 | 583 | pF |
| C _{rss} | reverse transfer capacitance | | - | 213 | 291 | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 30 \text{ V}; R_L = 1.2 \Omega; V_{GS} = 10 \text{ V};$ | - | 20 | - | ns |
| t _r | rise time | $R_{G(ext)} = 10 \Omega; T_j = 25 °C$ | - | 51 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 20 | - | ns |
| t _f | fall time | | - | 33 | - | ns |
| L _D | internal drain inductance | from drain lead 6 mm from package to center of die; $T_j = 25 ^{\circ}\text{C}$ | - | 4.5 | - | nΗ |
| | | from upper edge of drain mounting base to centre of die; $T_j = 25$ °C | - | 2.5 | - | nΗ |
| L _S | internal source inductance | from source lead 6 mm from package to source bond pad; $T_j = 25 ^{\circ}\text{C}$ | - | 7.5 | - | nΗ |
| Source-d | rain diode | | | | | |
| V_{SD} | source-drain voltage | $I_S = 25 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ °C}$; see Figure 13 | - | 0.85 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_S = 20 \text{ A}$; $dI_S/dt = -100 \text{ A/}\mu\text{s}$; $V_{GS} = -10 \text{ V}$; | - | 53 | - | ns |
| Q _r | recovered charge | $V_{DS} = 20 \text{ V}; T_j = 25 \text{ °C}$ | - | 44 | - | nC |

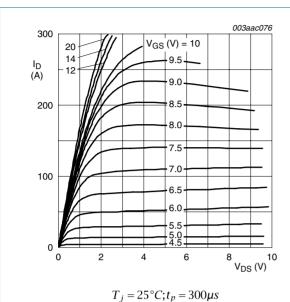
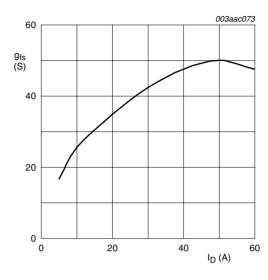


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values



 $T_j = 25 \,^{\circ}C; V_{DS} = 25 \, V$

Fig 6. Forward transconductance as a function of drain current; typical values

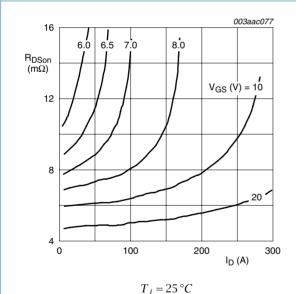


Fig 7. Drain-source on-state resistance as a function of drain current; typical values

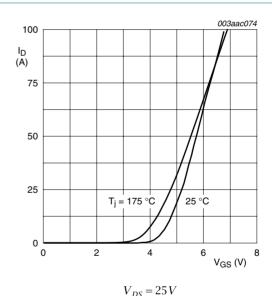
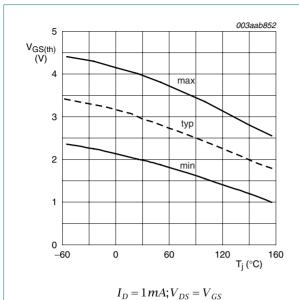
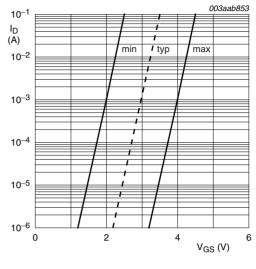


Fig 8. Transfer characteristics: drain current as a function of gate-source voltage; typical values



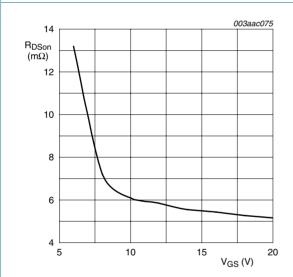
o-course threshold voltage a

Fig 9. Gate-source threshold voltage as a function of junction temperature



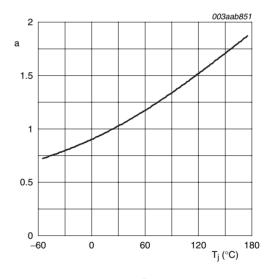
$$T_j = 25 \,^{\circ}C; V_{DS} = V_{GS}$$

Fig 10. Sub-threshold drain current as a function of gate-source voltage



 $T_j = 25 \,^{\circ}C; I_D = 25A$

Fig 11. Drain-source on-state resistance as a function of gate-source voltage; typical values



 $a = \frac{R_{DSon}}{R_{DSon(2.5^{\circ}C)}}$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature

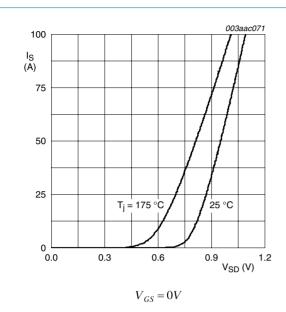
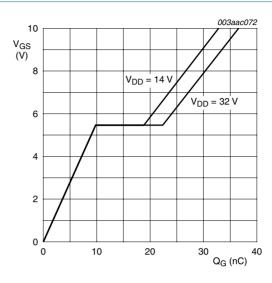
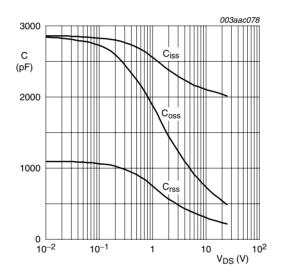


Fig 13. Reverse diode current as a function of reverse diode voltage; typical values



 $T_j = 25 \,^{\circ}C; I_D = 25A$

Fig 14. Gate-source voltage as a function of turn-on gate charge; typical values



 $V_{GS} = 0V; f = 1MHz$

Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

7. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) **SOT404** mounting D_1 base H_{D}^{\prime} 2.5 5 mm scale **DIMENSIONS (mm are the original dimensions)**

| OUTLINE | | REFER | RENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-------|--------|------------|-----------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT404 | | | | | -05-02-11 -06-03-16 |

Q

2.60

 H_D

15.80

Lp

2.90

Fig 16. Package outline SOT404 (D2PAK)

A₁

1.40

b

0.85

D

max.

С

0.64

Е

10.30

 D_1

1.60

UNIT

Α

4.50

8. Revision history

Table 7. Revision history

| | • | | | |
|-------------------|-------------------------------|------------------------|-------------------------|-------------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BUK7608-40B_4 | 20080924 | Product data sheet | - | BUK75_7608-40B_3 |
| Modifications: | Type numb | er BUK7608-40B separat | ed from data sheet BUK7 | 5_7608-40B_3 |
| BUK75_7608-40B_3 | 20071128 | Product data sheet | - | BUK75_7608-40B_2 |
| BUK75_7608-40B_2 | 20071116 | Product data sheet | - | BUK75_7608_40B-01 |
| BUK75_7608_40B-01 | 20030319 | Product data sheet | - | - |

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9.1 Data sheet status

| Document status [1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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BUK7608-40B

N-channel TrenchMOS standard level FET

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